



TSM103/A

DUAL OPERATIONAL AMPLIFIER AND VOLTAGE REFERENCE

NOT FOR NEW DESIGN - REPLACED BY TSM103W

OPERATIONAL AMPLIFIER

- LOW INPUT OFFSET VOLTAGE : 0.5mV
typ. for TSM103A
- LOW SUPPLY CURRENT : 350 μ A/op.
(@ $V_{CC} = 5V$)
- MEDIUM BANDWIDTH (unity gain) : 0.9MHz
- LARGE OUTPUT VOLTAGE SWING : 0V to
($V_{CC} - 1.5V$)
- INPUT COMMON MODE VOLTAGE RANGE
INCLUDES GROUND
- WIDE POWER SUPPLY RANGE : 3 to 32V
 ± 1.5 TO $\pm 16V$

VOLTAGE REFERENCE

- FIXED OUTPUT VOLTAGE REFERENCE 2.5V
- 0.4% AND 1% VOLTAGE PRECISION
- SINK CURRENT CAPABILITY : 1 to 100mA
- TYPICAL OUTPUT IMPEDANCE : 0.2 Ω

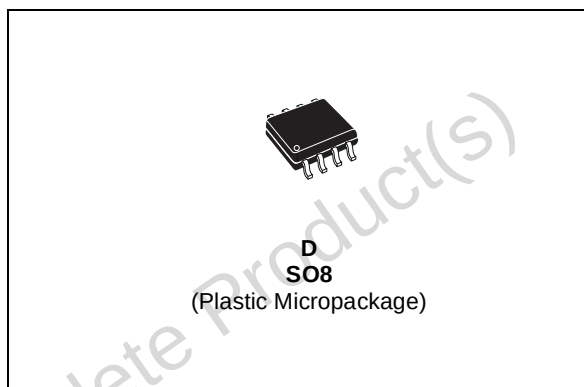
DESCRIPTION

The TSM103 is a monolithic IC that includes one independent op-amp and another op-amp for which the non inverting input is wired to a 2.5V fixed Voltage Reference. This device is offering space and cost saving in many applications like power supply management or data acquisition systems.

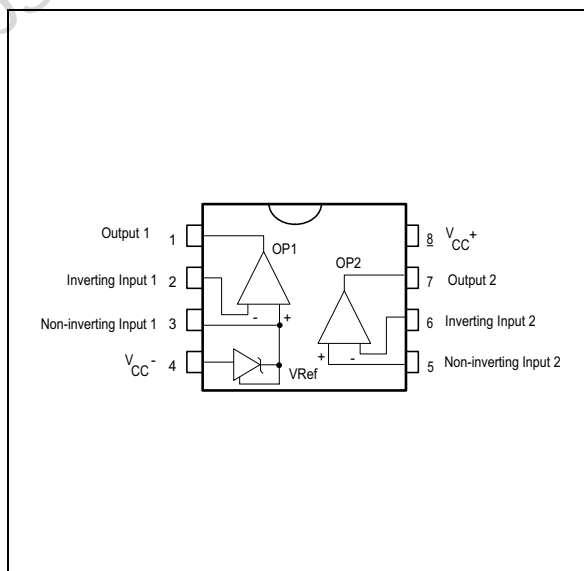
ORDER CODE

Part Number	Temperature Range	Package
		D
TSM103I/AI	-40°C, +105°C	•

D = Small Outline Package (SO) - also available in Tape & Reel (DT)



PIN CONNECTIONS (top view)



ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter	Value	Unit
V_{CC}	Supply Voltage	36	V
V_{id}	Differential Input Voltage	36	V
V_i	Input Voltage	-03. to +36	V
T_{oper}	Operating Free-air Temperature Range	-55 to +125	°C
T_j	Maximum Junction Temperature	150	°C
R_{thja}	Thermal Resistance Junction to Ambient (SO package)	175	°C/W

ELECTRICAL CHARACTERISTICS

Symbol	Parameter	Min.	Typ.	Max.	Unit
I_{CC}	Total Supply Current, excluding Current in the Voltage Reference VCC+ = 5V, no load Tmin. < Tamb < Tmax. VCC+ = 30V, no load Tmin. < Tamb < Tmax		0.7	1.2 2	mA

OPERATOR 2 (independent op-amp)
 $V_{CC}^+ = +5V$, $V_{CC} = \text{Ground}$, $V_o = 1.4V$, $T_{amb} = 25^\circ C$ (unless otherwise specified)

Symbol	Parameter	Min.	Typ.	Max.	Unit
V_{io}	Input Offset Voltage TSM103, $T_{amb} = 25^\circ C$ $T_{min.} \leq T_{amb} \leq T_{max.}$ TSM103A, $T_{amb} = 25^\circ C$ $T_{min.} \leq T_{amb} \leq T_{max.}$		1 0.5	4 5 2 3	mV
DV_{io}	Input Offset Voltage Drift		7		$\mu V/^\circ C$
I_{io}	Input Offset Current $T_{min.} \leq T_{amb} \leq T_{max.}$		2	30 50	nA
I_{ib}	Input Bias Current $T_{min.} \leq T_{amb} \leq T_{max.}$		20	150 200	nA
A_{vd}	Large Signal Voltage Gain $V_{CC} = 15V$, $R_L = 2k$, $V_o = 1.4V$ to $11.4V$ $T_{min.} \leq T_{amb} \leq T_{max.}$	50 25	100		V/mV
SVR	Supply Voltage Rejection Ratio $V_{CC} = 5V$ to $30V$	65	100		dB
V_{icm}	Input Common Mode Voltage Range $V_{CC} = +30V$ - see note ¹⁾ $T_{min.} \leq T_{amb} \leq T_{max.}$	0 0		$(V_{CC}^+) - 1.5$ $(V_{CC}^+) - 2$	V
CMR	Common Mode Rejection Ratio $T_{min.} \leq T_{amb} \leq T_{max.}$	70 60	85		dB
I_{source}	Output Current Source $V_{CC} = +15V$, $V_o = 2V$, $V_{id} = +1V$	20	40		mA
I_o	Short Circuit to Ground $V_{CC} = +15V$		40	60	mA
I_{sink}	Output Current Sink $V_{id} = -1V$, $V_{CC} = +15V$, $V_o = 2V$	10	20		mA
V_{OH}	High Level Output Voltage $V_{CC}^+ = 30V$ $T_{amb} = 25^\circ C$, $R_L = 10k$ $T_{min.} \leq T_{amb} \leq T_{max.}$	27 27	28		V
V_{OL}	Low Level Output Voltage $R_L = 10k$ $T_{min.} \leq T_{amb} \leq T_{max.}$		5	20 20	mV
SR	Slew Rate at Unity Gain $V_i = 0.5$ to $3V$, $V_{CC} = 15V$ $R_L = 2k$, $C_L = 100pF$, unity gain	0.2	0.4		V/ μs
GBP	Gain Bandwidth Product $V_{CC} = 30V$, $R_L = 2k$, $C_L = 100pF$ $f = 100kHz$, $V_{in} = 10mV$	0.5	0.9		MHz
THD	Total Harmonic Distortion $f = 1kHz$ $A_V = 20dB$, $R_L = 2k$, $V_{CC} = 30V$ $C_L = 100pF$, $V_o = 2V_{pp}$		0.02		%

1. The input common-mode voltage of either input signal voltage should not be allowed to go negative by more than 0.3V. The upper end of the common-mode voltage range is $V_{CC}^+ - 1.5V$. But either of both inputs can go to +36V without damage.

OPERATOR 1 (op-amp with non-inverting input connected to the internal Vref) $V_{CC}^+ = +5V$, $V_{CC}^- = \text{Ground}$, $T_{amb} = 25^\circ\text{C}$ (unless otherwise specified)

Symbol	Parameter	Min.	Typ.	Max.	Unit
V_{io}	Input Offset Voltage $V_{icm} = 0V$ TSM103, $T_{amb} = 25^\circ\text{C}$ $T_{min.} \leq T_{amb} \leq T_{max.}$ TSM103A, $T_{amb} = 25^\circ\text{C}$ $T_{min.} \leq T_{amb} \leq T_{max.}$		1 0.5	4 5 2 3	mV
DV_{io}	Input Offset Voltage Drift		7		$\mu\text{V}/^\circ\text{C}$
I_{ib}	Input Bias Current negative input		20		nA
A_{vd}	Large Signal Voltage Gain $V_{icm} = 0V$ $V_{CC} = 15V$, $R_L = 2k$		100		V/mV
SVR	Supply Voltage Rejection Ratio $V_{icm} = 0V$ $V_{CC}^+ = 5V$ to $30V$	65	100		dB
I_{source}	Output Current Source $V_o = 2V$ $V_{CC} = +15V$, $V_{id} = +1V$	20	40		mA
I_o	Short Circuit to Ground $V_{CC} = +15V$		40	60	mA
I_{sink}	Output Current Sink $V_{id} = -1V$, $V_{CC} = +15V$, $V_o = 2V$	10	20		mA
V_{OH}	High Level Output Voltage $V_{CC}^+ = 30V$ $T_{amb} = 25^\circ\text{C}$, $R_L = 10k$ $T_{min.} \leq T_{amb} \leq T_{max.}$	27 27	28		V
V_{OL}	Low Level Output Voltage $R_L = 10k$ $T_{min.} \leq T_{amb} \leq T_{max.}$		5	20 20	mV
SR	Slew Rate at Unity Gain $V_i = 0.5$ to $2V$, $V_{CC} = 15V$ $R_L = 2k$, $C_L = 100pF$, unity gain	0.2	0.4		V/ μs
GBP	Gain Bandwidth Product $V_{CC} = 30V$, $R_L = 2k$, $C_L = 100pF$ $f = 100kHz$, $V_{in} = 10mV$	0.5	0.9		MHz
THD	Total Harmonic Distortion $f = 1kHz$ $A_V = 20dB$, $R_L = 2k$, $V_{CC} = 30V$ $C_L = 100pF$, $V_o = 2V_{pp}$		0.02		%

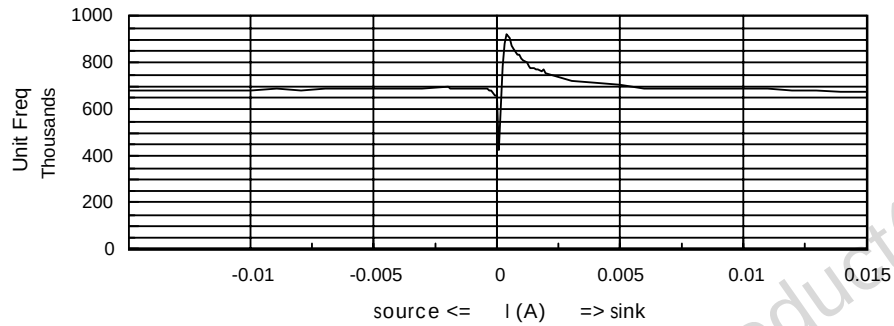
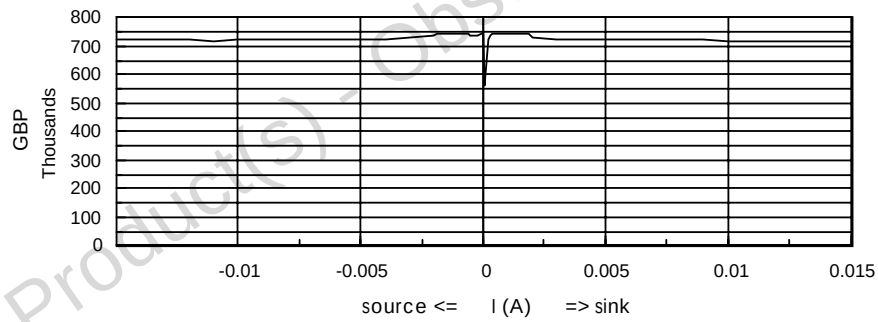
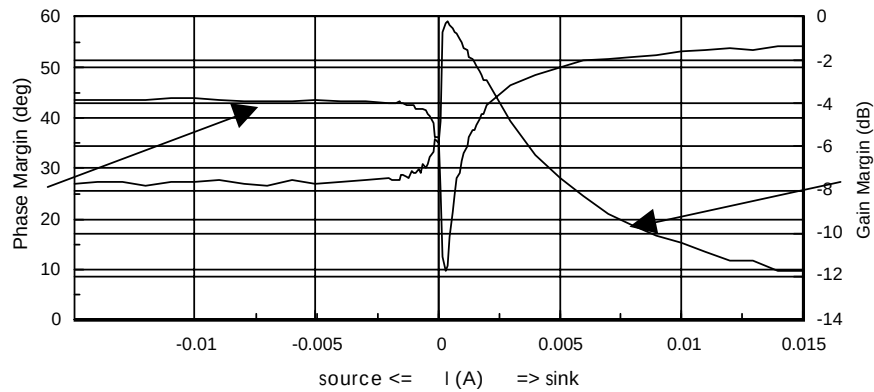
VOLTAGE REFERENCE

Symbol	Parameter	Value	Unit
I_k	Cathode Current	1 to 100	mA

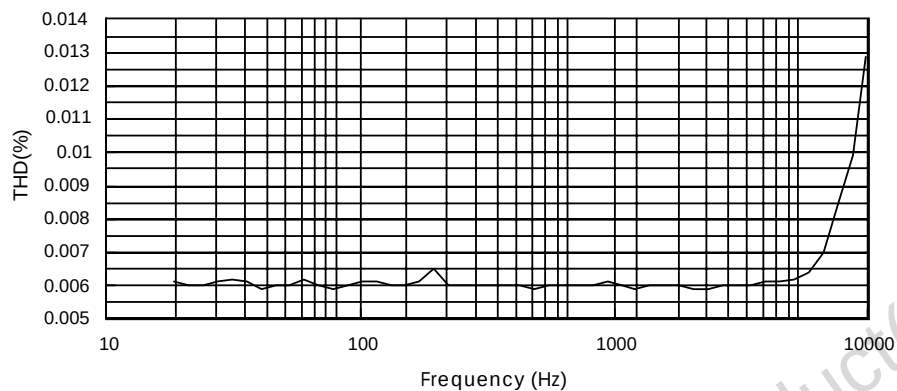
Symbol	Parameter	Min.	Typ.	Max.	Unit
V_{ref}	Reference Input Voltage TSM103, $T_{amb} = 25^{\circ}\text{C}$ $T_{min.} \leq T_{amb} \leq T_{max.}$ TSM103A, $T_{amb} = 25^{\circ}\text{C}$ $T_{min.} \leq T_{amb} \leq T_{max.}$	2.475 2.45 2.49 2.48	2.5 2.5	2.525 2.55 2.51 2.52	V
ΔV_{ref}	Reference Input Voltage Deviation Over Temperature Range $V_{KA} = V_{ref}$; $I_k = 10\text{mA}$ $T_{min.} \leq T_{amb} \leq T_{max.}$		7	30	mV
I_{min}	Minimum Cathode Current for Regulation $V_{KA} = V_{ref}$		0.5	1	mA
$ Z_{KA} $	Dynamic Impedance - note ¹⁾ $V_{KA} = V_{ref}$, $\Delta I_K = 1$ to 100mA , $f < 1\text{kHz}$		0.2	0.5	Ω

1. The dynamic impedance is defined as $|Z_{KA}| = \Delta V_{KA} / \Delta I_K$

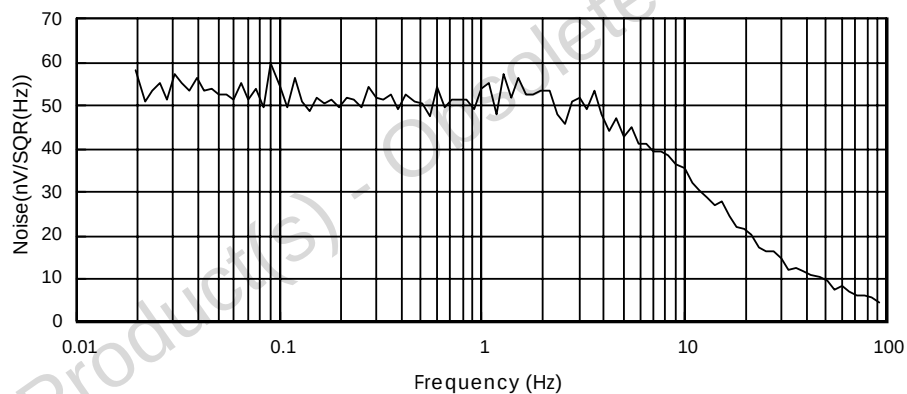
OPERATIONAL AMPLIFIERS

Unit Frequency = $F(I)$ $V_{CC} = \pm 15V$, $R_L = 2k$, $C_L = 100pF$ GBP = $F(I)$ $V_{CC} = \pm 15V$, $R_L = 2k$, $C_L = 100pF$ Phase and Gain Margin = $F(I)$ $V_{CC} = \pm 15V$, $R_L = 2k$, $C_L = 100pF$ 

Total Harmonic Distorsion THD = F(freq)

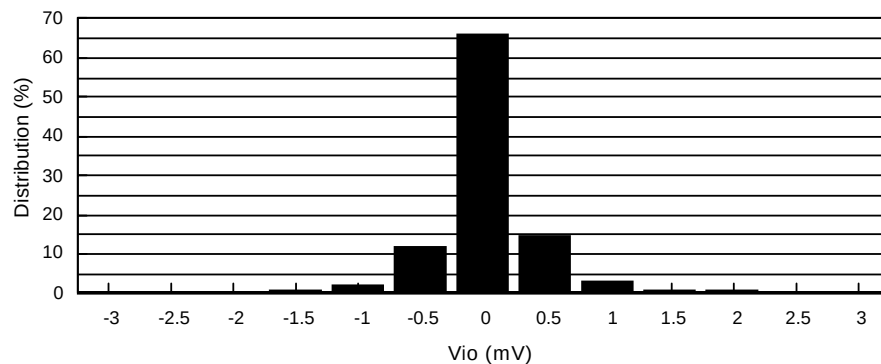


Noise = F(frequency)

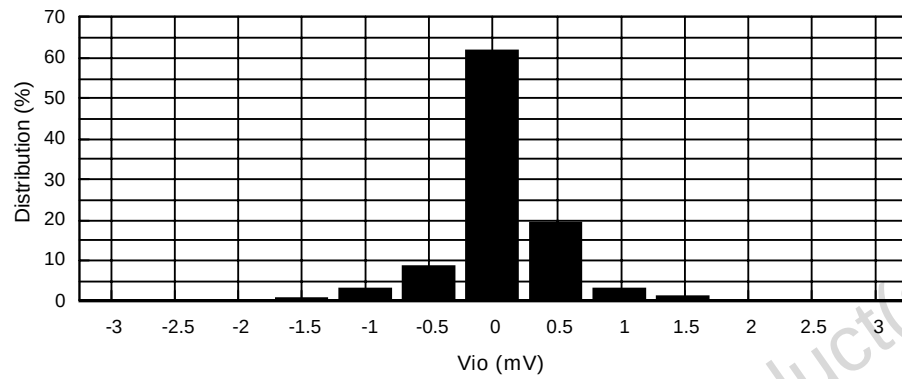
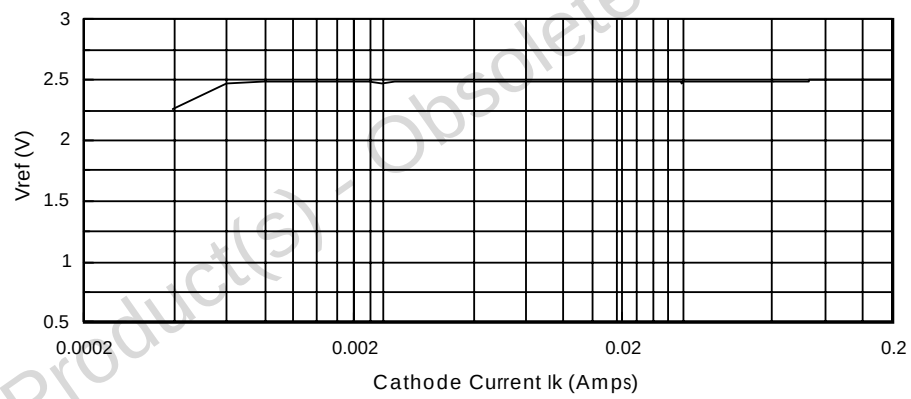
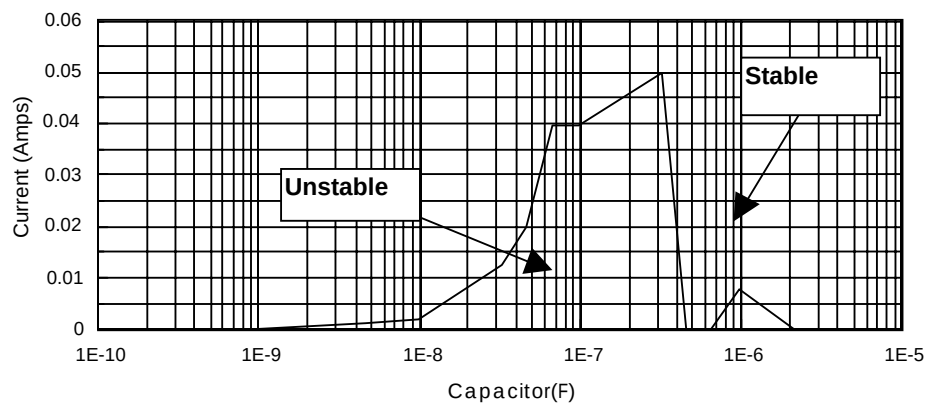


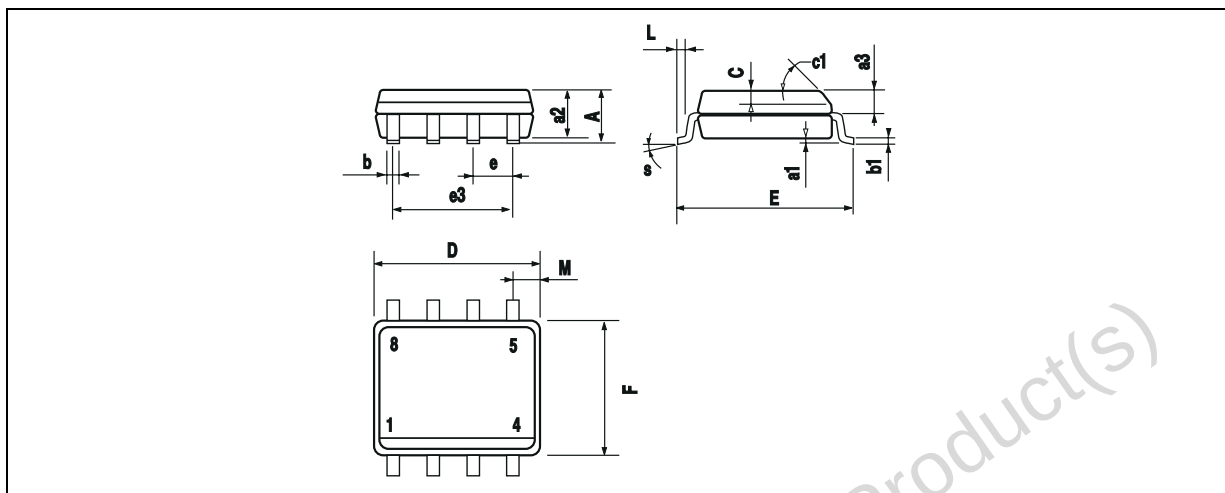
Vio Distribution - Operator 1

Vcc+=5V, Vcc-=0V



Vio Distribution - Operator 2

 $V_{CC}=+5V, V_{CC}=-0V$  $V_{ref} = F(I_k)$  $V_{ref} \text{ Stability} = f(I, C)$ 

PACKAGE MECHANICAL DATA**8 PINS - PLASTIC MICROPACKAGE (SO)**

Dim.	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A			1.75			0.069
a1	0.1		0.25	0.004		0.010
a2			1.65			0.065
a3	0.65		0.85	0.026		0.033
b	0.35		0.48	0.014		0.019
b1	0.19		0.25	0.007		0.010
C	0.25		0.5	0.010		0.020
c1	45° (typ.)					
D	4.8		5.0	0.189		0.197
E	5.8		6.2	0.228		0.244
e		1.27			0.050	
e3		3.81			0.150	
F	3.8		4.0	0.150		0.157
L	0.4		1.27	0.016		0.050
M			0.6			0.024
S	8° (max.)					

Information furnished is believed to be accurate and reliable. However, STMicroelectronics assumes no responsibility for the consequences of use of such information nor for any infringement of patents or other rights of third parties which may result from its use. No license is granted by implication or otherwise under any patent or patent rights of STMicroelectronics. Specifications mentioned in this publication are subject to change without notice. This publication supersedes and replaces all information previously supplied. STMicroelectronics products are not authorized for use as critical components in life support devices or systems without express written approval of STMicroelectronics.

The ST logo is a registered trademark of STMicroelectronics

© 2003 STMicroelectronics - All Rights Reserved

STMicroelectronics GROUP OF COMPANIES

Australia - Brazil - China - Finland - France - Germany - Hong Kong - India - Italy - Japan - Malaysia - Malta - Morocco
Singapore - Spain - Sweden - Switzerland - United Kingdom

<http://www.st.com>





Компания «ЭлектроПласт» предлагает заключение долгосрочных отношений при поставках импортных электронных компонентов на взаимовыгодных условиях!

Наши преимущества:

- Оперативные поставки широкого спектра электронных компонентов отечественного и импортного производства напрямую от производителей и с крупнейших мировых складов;
- Поставка более 17-ти миллионов наименований электронных компонентов;
- Поставка сложных, дефицитных, либо снятых с производства позиций;
- Оперативные сроки поставки под заказ (от 5 рабочих дней);
- Экспресс доставка в любую точку России;
- Техническая поддержка проекта, помощь в подборе аналогов, поставка прототипов;
- Система менеджмента качества сертифицирована по Международному стандарту ISO 9001;
- Лицензия ФСБ на осуществление работ с использованием сведений, составляющих государственную тайну;
- Поставка специализированных компонентов (Xilinx, Altera, Analog Devices, Intersil, Interpoint, Microsemi, Aeroflex, Peregrine, Syfer, Eurofarad, Texas Instrument, Miteq, Cobham, E2V, MA-COM, Hittite, Mini-Circuits, General Dynamics и др.);

Помимо этого, одним из направлений компании «ЭлектроПласт» является направление «Источники питания». Мы предлагаем Вам помощь Конструкторского отдела:

- Подбор оптимального решения, техническое обоснование при выборе компонента;
- Подбор аналогов;
- Консультации по применению компонента;
- Поставка образцов и прототипов;
- Техническая поддержка проекта;
- Защита от снятия компонента с производства.



Как с нами связаться

Телефон: 8 (812) 309 58 32 (многоканальный)

Факс: 8 (812) 320-02-42

Электронная почта: org@eplast1.ru

Адрес: 198099, г. Санкт-Петербург, ул. Калинина, дом 2, корпус 4, литера А.